

MMUN2211LT1 Series

查询MMUN2211LT1C"供应商

Preferred Devices

Bias Resistor Transistor

NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SOT-23 package which is designed for low power surface mount applications.

Features

- Simplifies Circuit Design
- Reduces Board Space and Component Count
- Pb-Free Packages are Available

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	50	Vdc
Collector-Emitter Voltage	V _{CEO}	50	Vdc
Collector Current	I _C	100	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation T _A = 25°C Derate above 25°C	P _D	246 (Note 1) 400 (Note 2) 1.5 (Note 1) 2.0 (Note 2)	mW °C/W
Thermal Resistance, Junction-to-Ambient	R _{θJA}	508 (Note 1) 311 (Note 2)	°C/W
Thermal Resistance, Junction-to-Lead	R _{θJL}	174 (Note 1) 208 (Note 2)	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

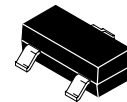
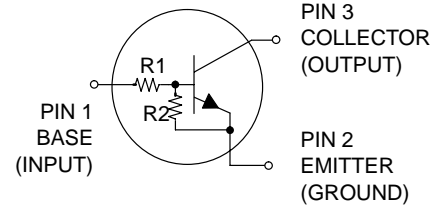
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. FR-4 @ minimum pad
2. FR-4 @ 1.0 x 1.0 inch pad



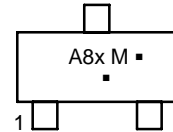
ON Semiconductor®

<http://onsemi.com>



SOT-23
CASE 318
STYLE 6

MARKING DIAGRAM



A8x = Specific Device Code
M = Date Code
▪ = Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

MMUN2211LT1 Series

查询"MMUN2211LT1G"供应商

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector-Base Cutoff Current ($V_{CB} = 50\text{ V}$, $I_E = 0$)	I_{CBO}	-	-	100	nAdc
Collector-Emitter Cutoff Current ($V_{CE} = 50\text{ V}$, $I_B = 0$)	I_{CEO}	-	-	500	nAdc
Emitter-Base Cutoff Current ($V_{EB} = 6.0\text{ V}$, $I_C = 0$)	I_{EBO}	-	-	0.5	mAdc
MMUN2211LT1		-	-	0.2	
MMUN2212LT1		-	-	0.1	
MMUN2213LT1		-	-	0.2	
MMUN2214LT1		-	-	0.9	
MMUN2215LT1		-	-	1.9	
MMUN2216LT1		-	-	4.3	
MMUN2230LT1		-	-	2.3	
MMUN2231LT1		-	-	1.5	
MMUN2232LT1		-	-	0.18	
MMUN2233LT1		-	-	0.13	
MMUN2234LT1		-	-	4.0	
MMUN2238LT1		-	-	0.1	
MMUN2241LT1		-	-		
Collector-Base Breakdown Voltage ($I_C = 10\ \mu\text{A}$, $I_E = 0$)	$V_{(BR)CBO}$	50	-	-	Vdc
Collector-Emitter Breakdown Voltage (Note 3), ($I_C = 2.0\text{ mA}$, $I_B = 0$)	$V_{(BR)CEO}$	50	-	-	Vdc

ON CHARACTERISTICS (Note 3)

DC Current Gain ($V_{CE} = 10\text{ V}$, $I_C = 5.0\text{ mA}$)	MMUN2211LT1 MMUN2212LT1 MMUN2213LT1 MMUN2214LT1 MMUN2215LT1 MMUN2216LT1 MMUN2230LT1 MMUN2231LT1 MMUN2232LT1 MMUN2233LT1 MMUN2234LT1 MMUN2238LT1 MMUN2241LT1	h_{FE}	35 60 80 80 160 160 3.0 8.0 15 80 80 160 160	60 100 140 140 350 350 5.0 15 30 200 150 350 350	- - - - - - - - - - - - -	
Collector-Emitter Saturation Voltage ($I_C = 10\text{ mA}$, $I_B = 0.3\text{ mA}$) ($I_C = 10\text{ mA}$, $I_B = 5\text{ mA}$) MMUN2230LT1/MMUN2231LT1 ($I_C = 10\text{ mA}$, $I_B = 1\text{ mA}$) MMUN2215LT1/MMUN2216LT1 MMUN2232LT1/MMUN2233LT1/MMUN2234LT1/ MMUN2238LT1		$V_{CE(sat)}$	-	-	0.25	Vdc

3. Pulse Test: Pulse Width < 300 μs , Duty Cycle < 2.0%.

MMUN2211LT1 Series

查询MMUN2211LT1 供应商 (T_A = 25°C unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit	
ON CHARACTERISTICS (Note 4)						
Output Voltage (on) (V _{CC} = 5.0 V, V _B = 2.5 V, R _L = 1.0 k Ω)	MMUN2211LT1 MMUN2212LT1 MMUN2214LT1 MMUN2215LT1 MMUN2216LT1 MMUN2230LT1 MMUN2231LT1 MMUN2232LT1 MMUN2233LT1 MMUN2234LT1 MMUN2238LT1 (V _{CC} = 5.0 V, V _B = 3.5 V, R _L = 1.0 k Ω) (V _{CC} = 5.0 V, V _B = 5.0 V, R _L = 1.0 k Ω)	V _{OL}	-	-	0.2	Vdc
Output Voltage (off) (V _{CC} = 5.0 V, V _B = 0.5 V, R _L = 1.0 k Ω) (V _{CC} = 5.0 V, V _B = 0.050 V, R _L = 1.0 k Ω) (V _{CC} = 5.0 V, V _B = 0.25 V, R _L = 1.0 k Ω)	MMUN2230LT1 MMUN2215LT1 MMUN2216LT1 MMUN2233LT1 MMUN2238LT1	V _{OH}	4.9	-	-	Vdc
Input Resistor	MMUN2211LT1 MMUN2212LT1 MMUN2213LT1 MMUN2214LT1 MMUN2215LT1 MMUN2216LT1 MMUN2230LT1 MMUN2231LT1 MMUN2232LT1 MMUN2233LT1 MMUN2234LT1 MMUN2238LT1 MMUN2241LT1	R1	7.0 15.4 32.9 7.0 7.0 3.3 0.7 1.5 3.3 3.3 15.4 1.54 70	10 22 47 10 10 4.7 1.0 2.2 4.7 4.7 22 2.2 100	13 28.6 61.1 13 13 6.1 1.3 2.9 6.1 6.1 28.6 2.88 130	kΩ
Resistor Ratio	MMUN2211LT1/MMUN2212LT1/MMUN2213LT1 MMUN2214LT1 MMUN2215LT1/MMUN2216LT1/MMUN2238LT1 MMUN2241LT1 MMUN2230LT1/MMUN2231LT1/MMUN2232LT1 MMUN2233LT1 MMUN2234LT1	R1/R2	0.8 0.17 - - 0.8 0.055 0.38	1.0 0.21 - - 1.0 0.1 0.47	1.2 0.25 - - 1.2 0.185 0.56	

4. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%.

MMUN2211LT1 Series

[查询"MMUN2211LT1G"供应商](#)

TYPICAL ELECTRICAL CHARACTERISTICS MMUN2211LT1

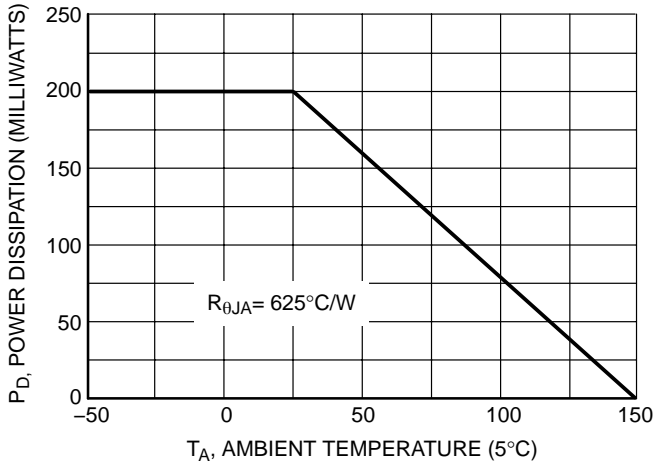


Figure 1. Derating Curve

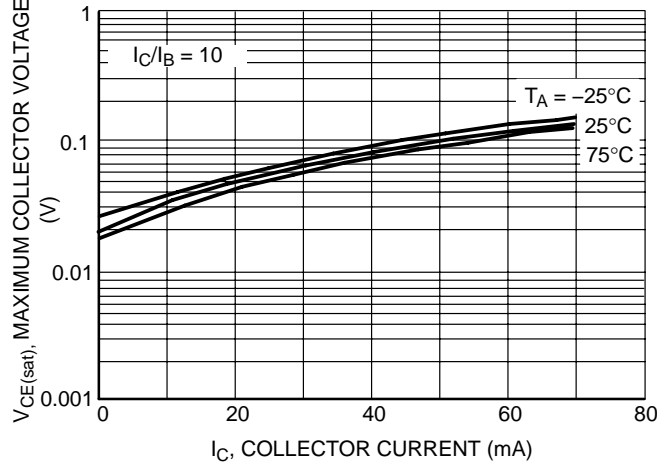


Figure 2. $V_{CE(sat)}$ vs. I_C

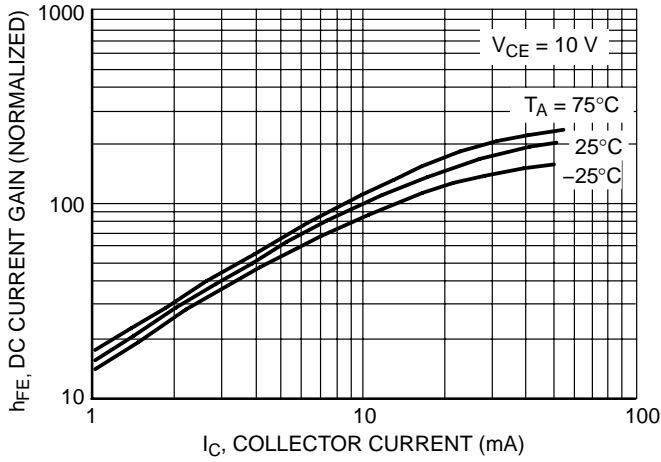


Figure 3. DC Current Gain

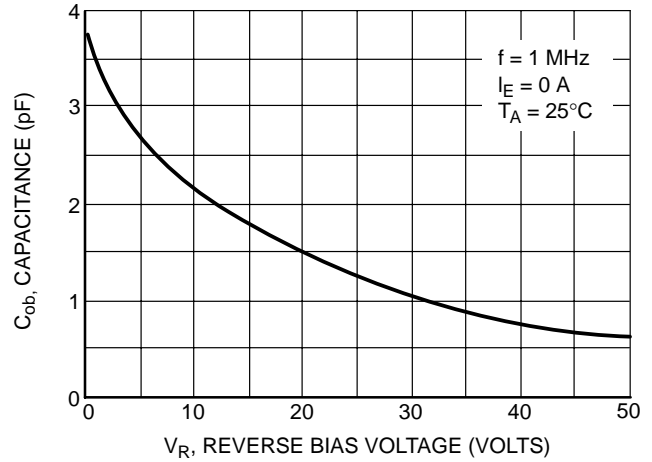


Figure 4. Output Capacitance

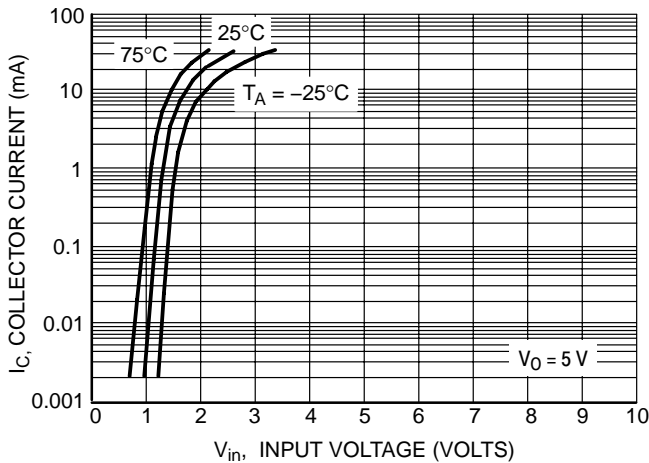


Figure 5. Output Current vs. Input Voltage

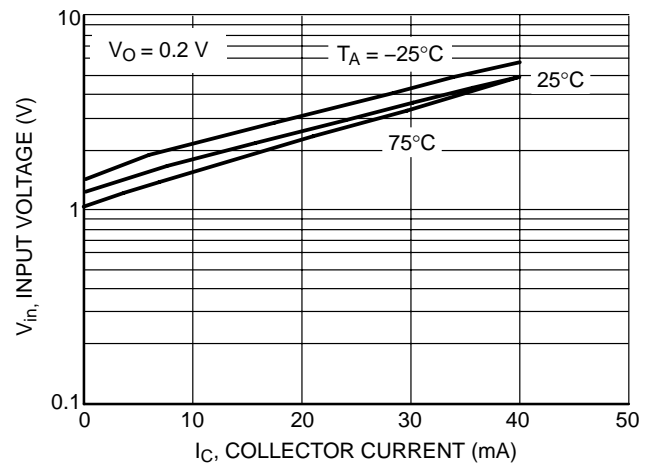


Figure 6. Input Voltage vs. Output Current

MMUN2211LT1 Series

查询"MMUN2211LT1G"供应商

TYPICAL ELECTRICAL CHARACTERISTICS MMUN2212LT1

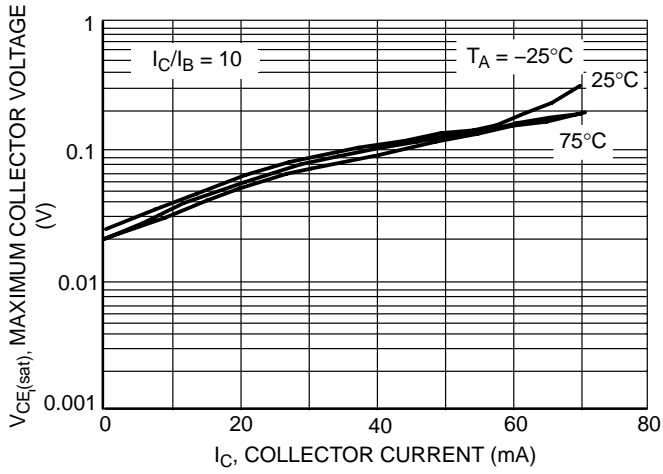


Figure 7. $V_{CE(sat)}$ vs. I_C

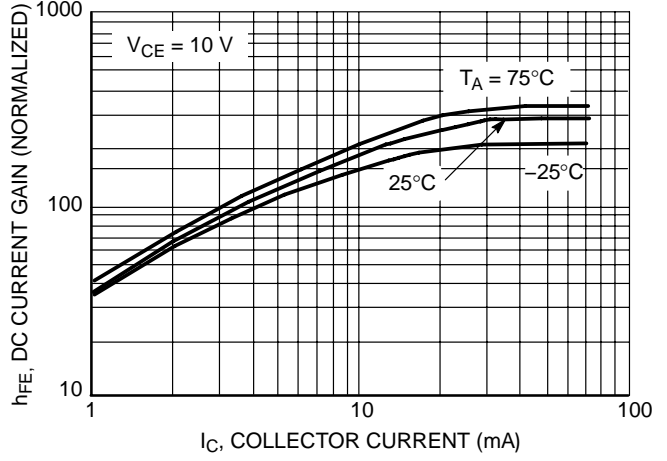


Figure 8. DC Current Gain

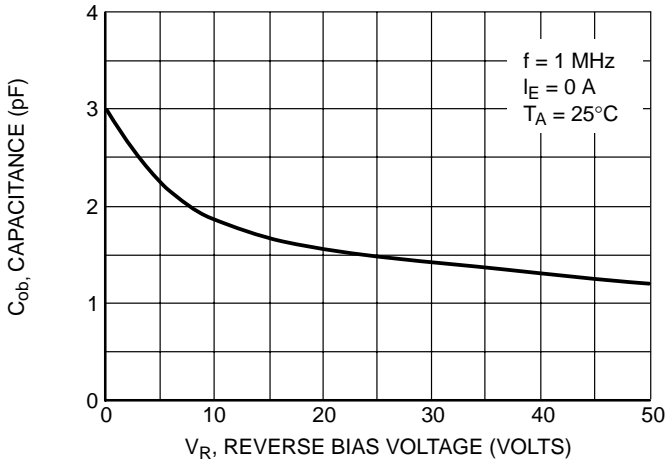


Figure 9. Output Capacitance

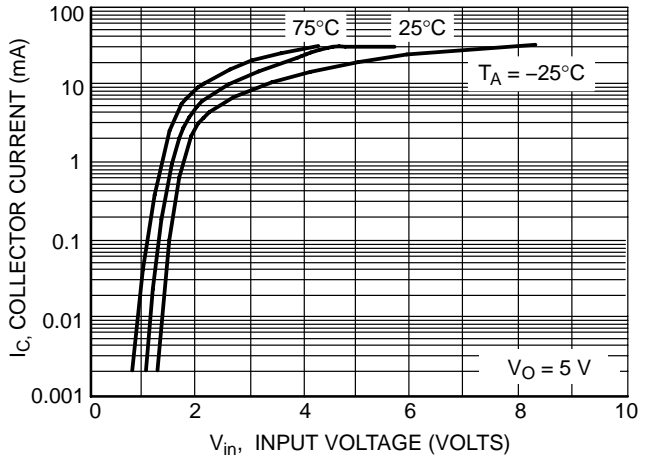


Figure 10. Output Current vs. Input Voltage

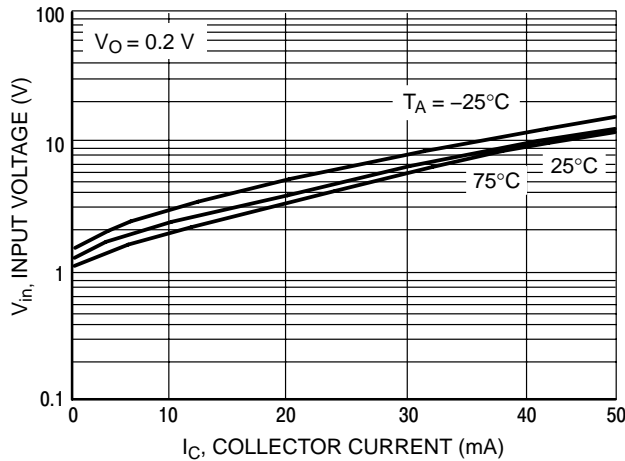


Figure 11. Input Voltage vs. Output Current

MMUN2211LT1 Series

[查询"MMUN2211LT1G"供应商](#)

TYPICAL ELECTRICAL CHARACTERISTICS MMUN2213LT1

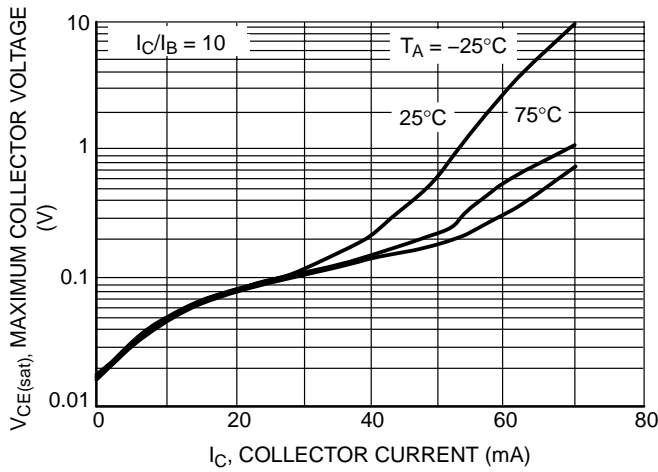


Figure 12. $V_{CE(sat)}$ vs. I_C

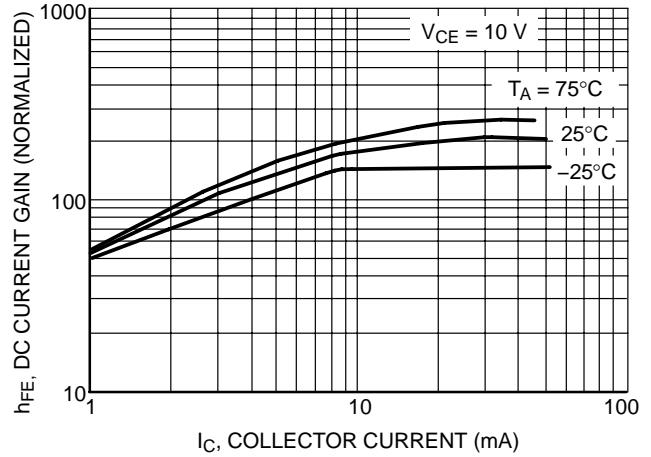


Figure 13. DC Current Gain

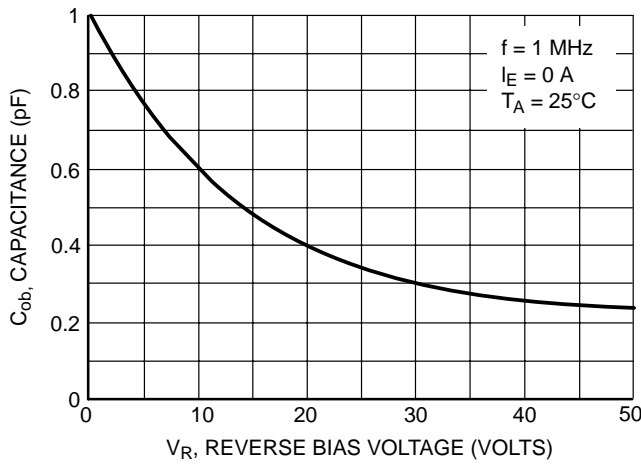


Figure 14. Output Capacitance

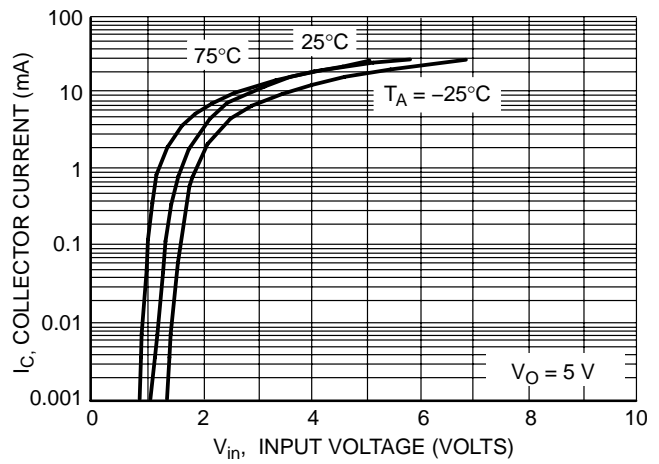


Figure 15. Output Current vs. Input Voltage

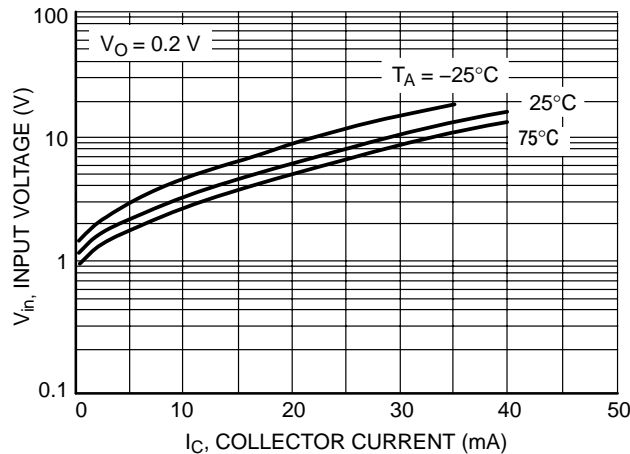


Figure 16. Input Voltage vs. Output Current

MMUN2211LT1 Series

查询"MMUN2211LT1G"供应商

TYPICAL ELECTRICAL CHARACTERISTICS MMUN2214LT1

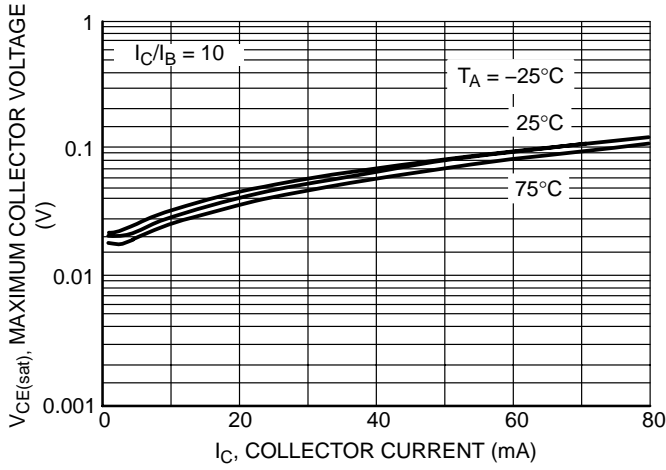


Figure 17. $V_{CE(sat)}$ vs. I_C

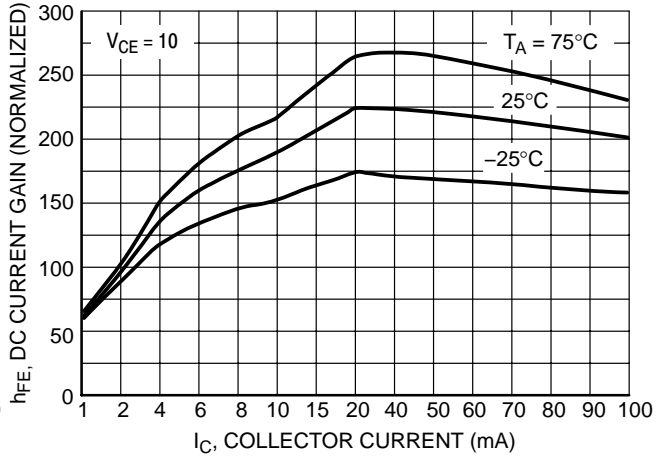


Figure 18. DC Current Gain

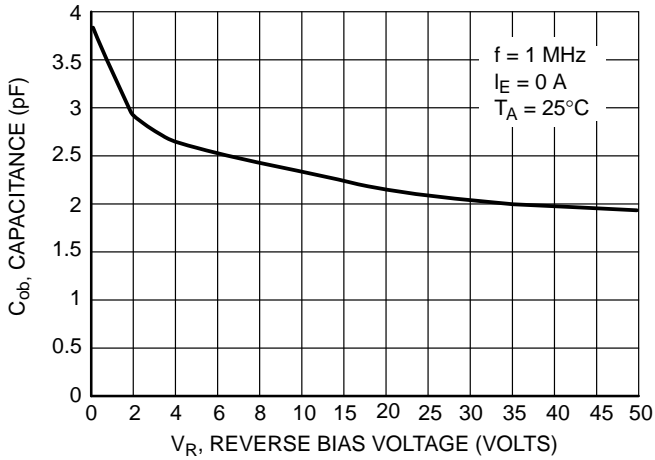


Figure 19. Output Capacitance

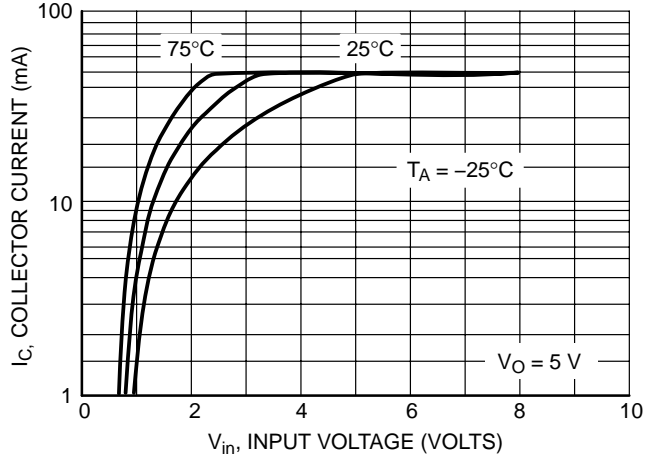


Figure 20. Output Current vs. Input Voltage

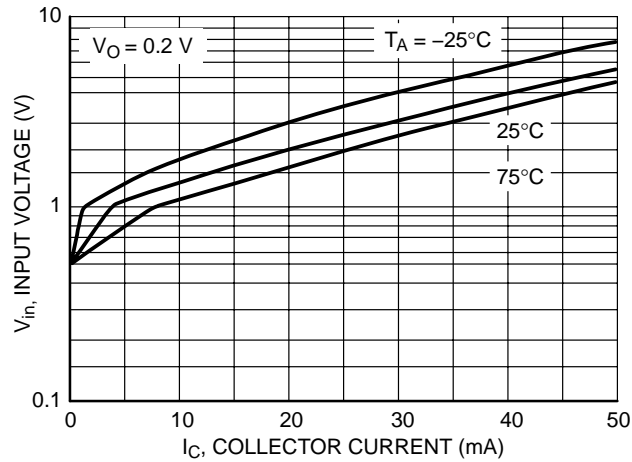


Figure 21. Input Voltage vs. Output Current

MMUN2211LT1 Series

[查询"MMUN2211LT1G"供应商](#)

TYPICAL ELECTRICAL CHARACTERISTICS MMUN2232LT1

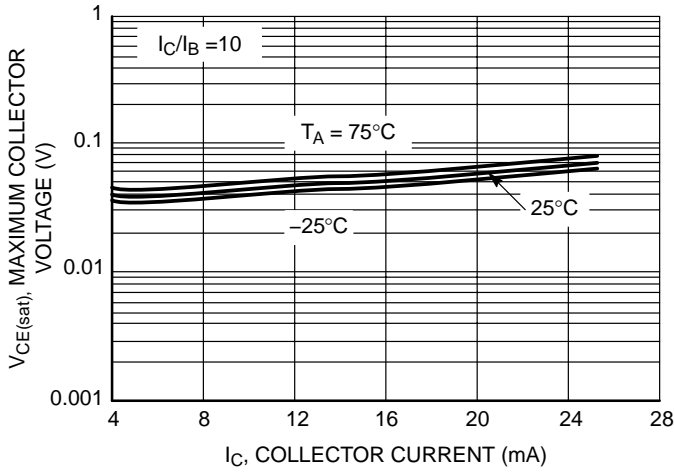


Figure 22. $V_{CE(sat)}$ vs. I_C

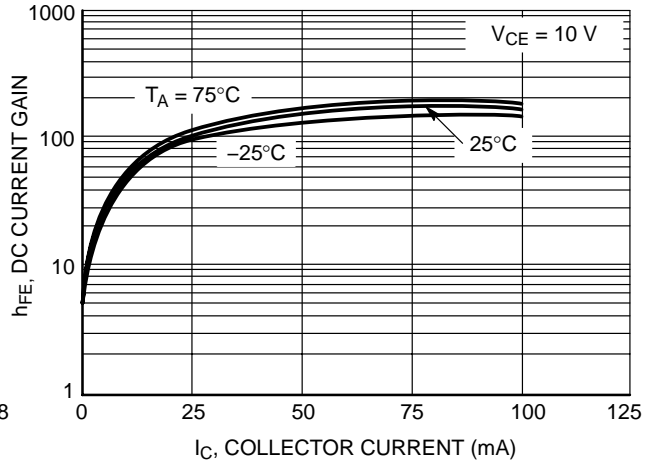


Figure 23. DC Current Gain

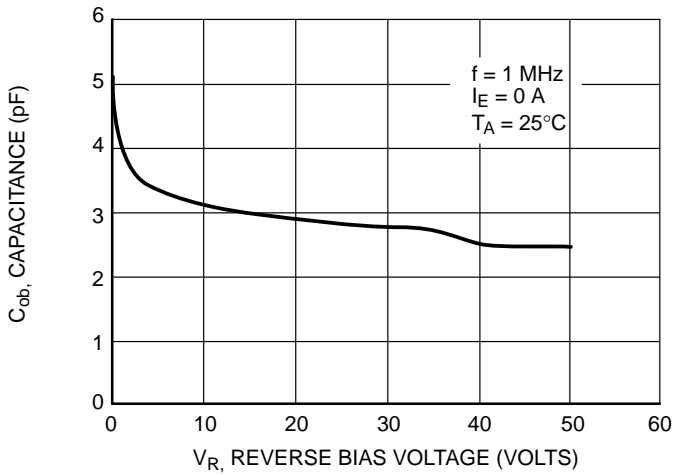


Figure 24. Output Capacitance

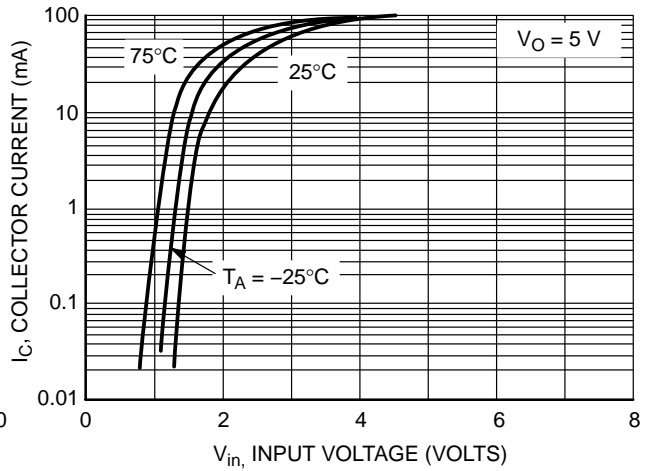


Figure 25. Output Current vs. Input Voltage

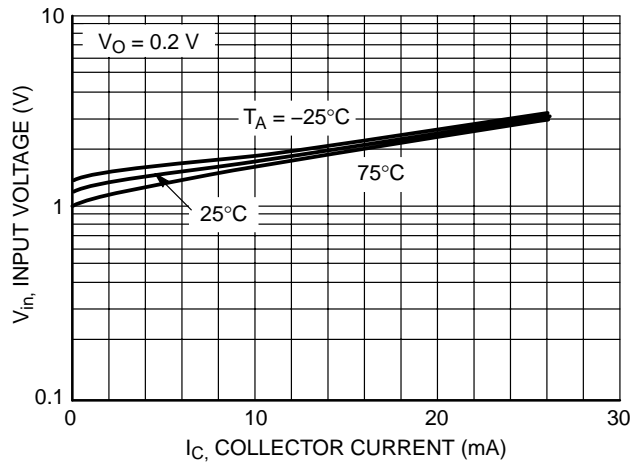


Figure 26. Output Voltage vs. Input Current

MMUN2211LT1 Series

[查询"MMUN2211LT1G"供应商](#)

TYPICAL ELECTRICAL CHARACTERISTICS MMUN2233LT1

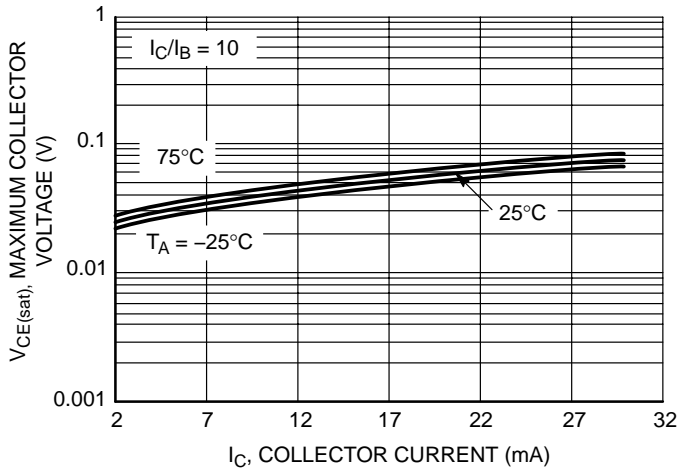


Figure 27. $V_{CE(sat)}$ vs. I_C

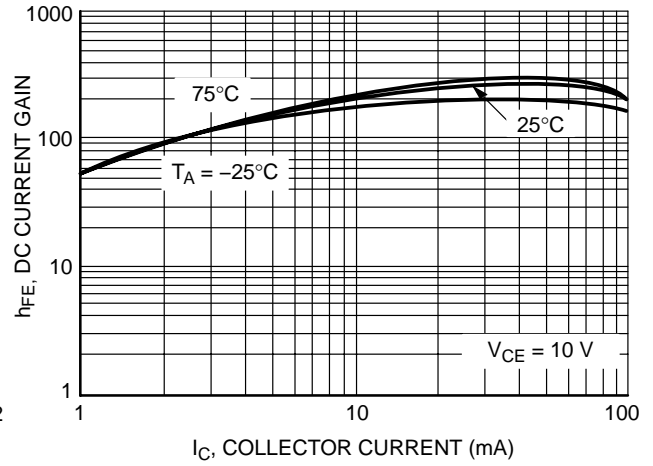


Figure 28. DC Current Gain

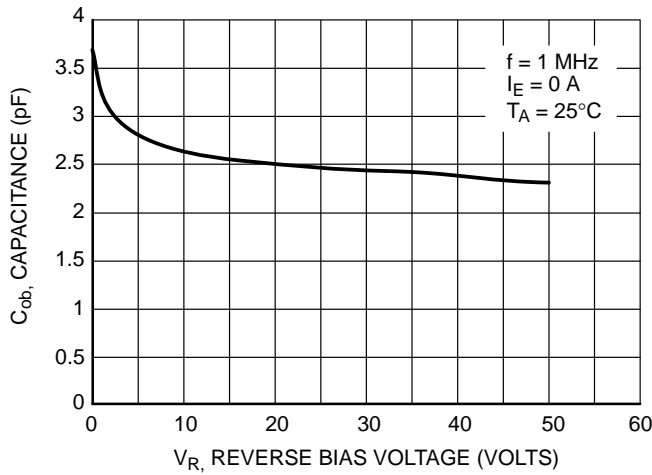


Figure 29. Output Capacitance

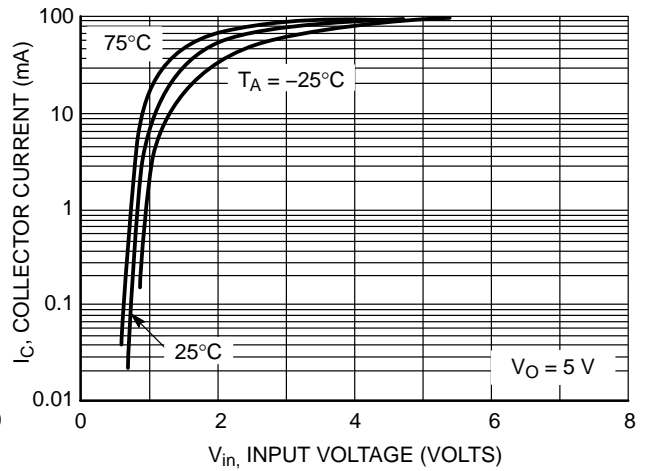


Figure 30. Output Current vs. Input Voltage

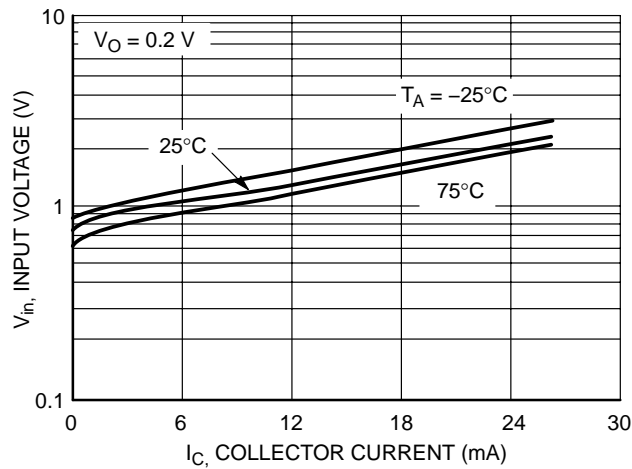


Figure 31. Input Voltage vs. Output Current

MMUN2211LT1 Series

[查询"MMUN2211LT1G"供应商](#)

TYPICAL APPLICATIONS FOR NPN BRTs

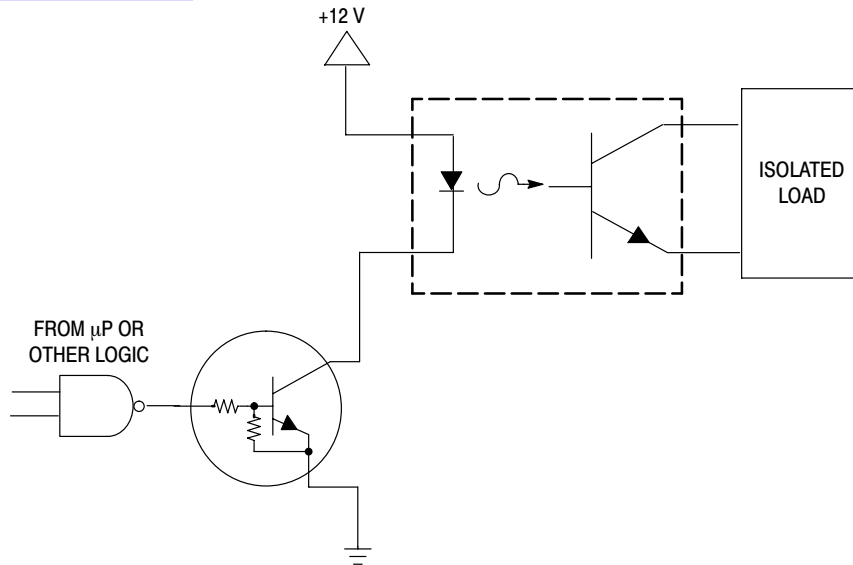


Figure 32. Level Shifter: Connects 12 or 24 Volt Circuits to Logic

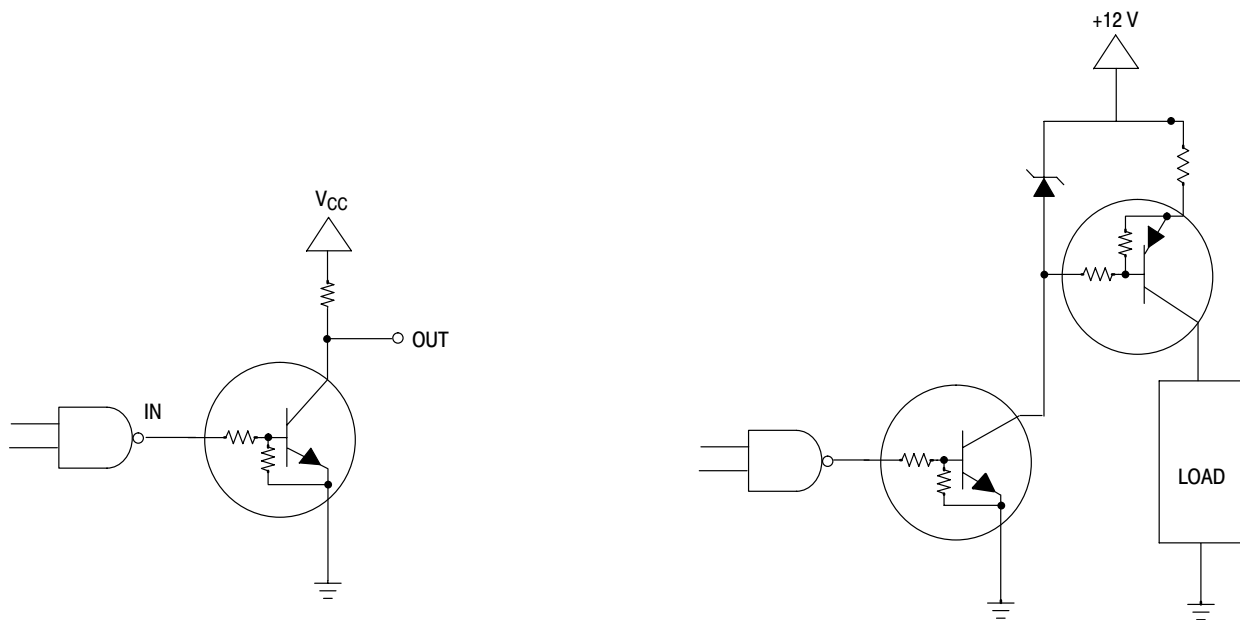


Figure 33. Open Collector Inverter: Inverts the Input Signal

Figure 34. Inexpensive, Unregulated Current Source

MMUN2211LT1 Series

ORDERING INFORMATION 供应商

Device	Marking	R1(k)	R2(k)	Package	Shipping [†]
MMUN2211LT1	A8A	10	10	SOT-23	3000 / Tape & Reel
MMUN2211LT1G		10	10	SOT-23 (Pb-Free)	
MMUN2211LT3		10	10	SOT-23	10,000 / Tape & Reel
MMUN2211LT3G		10	10	SOT-23 (Pb-Free)	
MMUN2212LT1	A8B	22	22	SOT-23	3000 / Tape & Reel
MMUN2212LT1G		22	22	SOT-23 (Pb-Free)	
MMUN2213LT1	A8C	47	47	SOT-23	
MMUN2213LT1G		47	47	SOT-23 (Pb-Free)	
MMUN2214LT1	A8D	10	47	SOT-23	
MMUN2214LT1G		10	47	SOT-23 (Pb-Free)	
MMUN2215LT1	A8E	10	∞	SOT-23	
MMUN2215LT1G		10	∞	SOT-23 (Pb-Free)	
MMUN2216LT1	A8F	4.7	∞	SOT-23	
MMUN2216LT1G		4.7	∞	SOT-23 (Pb-Free)	
MMUN2230LT1	A8G	1.0	1.0	SOT-23	
MMUN2230LT1G		1.0	1.0	SOT-23 (Pb-Free)	
MMUN2231LT1	A8H	2.2	2.2	SOT-23	
MMUN2231LT1G		2.2	2.2	SOT-23 (Pb-Free)	
MMUN2232LT1	A8J	4.7	4.7	SOT-23	
MMUN2232LT1G		4.7	4.7	SOT-23 (Pb-Free)	
MMUN2233LT1	A8K	4.7	47	SOT-23	
MMUN2233LT1G		4.7	47	SOT-23 (Pb-Free)	
MMUN2234LT1	A8L	22	47	SOT-23	
MMUN2234LT1G		22	47	SOT-23 (Pb-Free)	
MMUN2234LT3		22	47	SOT-23	10,000 / Tape & Reel
MMUN2234LT3G		22	47	SOT-23 (Pb-Free)	
MMUN2238LT1	A8R	2.2	∞	SOT-23	3000 / Tape & Reel
MMUN2238LT1G		2.2	∞	SOT-23 (Pb-Free)	
MMUN2241LT1	A8U	100	∞	SOT-23	
MMUN2241LT1G		100	∞	SOT-23 (Pb-Free)	

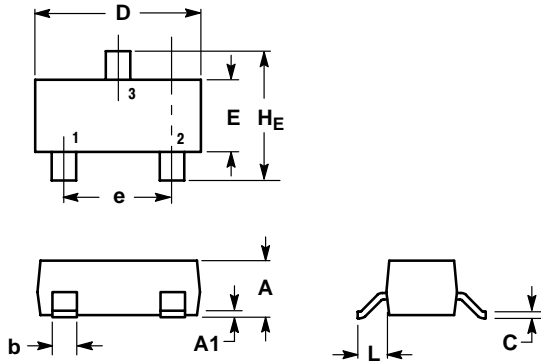
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MMUN2211LT1 Series

[查询"MMUN2211LT1G"供应商](#)

PACKAGE DIMENSIONS

SOT-23 (TO-236)
CASE 318-08
ISSUE AL



NOTES:

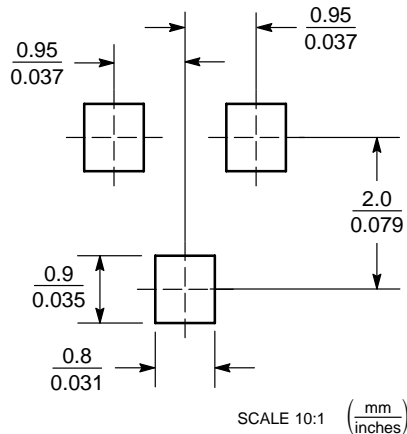
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
L	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 6:

1. BASE
2. EMITTER
3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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